Theme II: Nanomechanics



E3S Center Annual Retreat September 7, 2017



Berkeley Massachusetts Institute of Technology STANFORD UNIVERSITY





CALIFORNIA COMMUNITY COLLEGES CHANCELLOR'S OFFICE





Electronics Science

Recent Accomplishments



Electronics Science

Research Updates

Sub-50 mV NEM Switch Devices Bivas Saha

Squitch Design, Fabrication, Metrology Farnaz Niroui

Stritch Research Update David Zubia



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Theme II (Nanomechanics) Roadmap



A Science & Technology Center

Center for Energy Efficient Electronics Science

Theme II Legacy

- Foundational Science & Technology
 - Nanofabrication techniques (sub-1 nm surface roughness)
 - Nanoscale metrology (plasmonic ruler)
- > NEM Switches
 - Sub-10 mV proof-of-concept (enabled by EE+MSE+Chemistry)
 - Identification of challenges (e.g., molecular coating requirements)
- Integrated Systems
 - Demonstration of sub-100 mV relay-based integrated circuits
 - Reconfigurable interconnects for CMOS
- Research technology transfer to UTEP



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